## 74LVC2G66

Bilateral switch
Rev. 5 - 16 June 2010
Product data sheet

## 1. General description

The 74LVC2G66 is a low-power, low-voltage, high-speed Si-gate CMOS device.
The 74LVC2G66 provides two single pole, single-throw analog switch functions. Each switch has two input/output terminals ( nY and nZ ) and an active HIGH enable input ( nE ). When nE is LOW, the analog switch is turned off.

Schmitt-trigger action at the enable inputs makes the circuit tolerant of slower input rise and fall times across the entire $\mathrm{V}_{\mathrm{cc}}$ range from 1.65 V to 5.5 V .

## 2. Features and benefits

■ Wide supply voltage range from 1.65 V to 5.5 V

- Very low ON resistance:
- $7.5 \Omega$ (typical) at $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$
- $6.5 \Omega$ (typical) at $\mathrm{V}_{\mathrm{cc}}=3.3 \mathrm{~V}$
- $6 \Omega$ (typical) at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$
- Switch current capability of 32 mA
- High noise immunity
- CMOS low power consumption
- TTL interface compatibility at 3.3 V

■ Latch-up performance meets requirements of JESD78 Class I

- ESD protection:
- HBM JESD22-A114F exceeds 2000 V
- MM JESD22-A115-A exceeds 200 V
- Enable input accepts voltages up to 5.5 V
- Multiple package options
- Specified from $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ and $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$


## 3. Ordering information

Table 1. Ordering information

| Type number | Package |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | Temperature range | Name | Description | Version |
| 74LVC2G66DP | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | TSSOP8 | plastic thin shrink small outline package; 8 leads; body width 3 mm ; lead length 0.5 mm | SOT505-2 |
| 74LVC2G66DC | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | VSSOP8 | plastic very thin shrink small outline package; 8 leads; body width 2.3 mm | SOT765-1 |
| 74LVC2G66GT | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | XSON8 | plastic extremely thin small outline package; no leads; 8 terminals; body $1 \times 1.95 \times 0.5 \mathrm{~mm}$ | SOT833-1 |
| 74LVC2G66GD | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | XSON8U | plastic extremely thin small outline package; no leads; 8 terminals; UTLP based; body $3 \times 2 \times 0.5 \mathrm{~mm}$ | SOT996-2 |
| 74LVC2G66GM | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | XQFN8U | plastic extremely thin quad flat package; no leads; 8 terminals; UTLP based; body $1.6 \times 1.6 \times 0.5 \mathrm{~mm}$ | SOT902-1 |

## 4. Marking

Table 2. Marking codes

| Type number | Marking code ${ }^{[1]}$ |
| :--- | :--- |
| 74LVC2G66DP | V66 |
| 74LVC2G66DC | V66 |
| 74LVC2G66GT | V66 |
| 74LVC2G66GD | V66 |
| 74LVC2G66GM | V66 |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

## 5. Functional diagram



Fig 1. Logic symbol


Fig 2. IEC logic symbol


Fig 3. Logic diagram (one switch)

## 6. Pinning information

### 6.1 Pinning




Fig 6. Pin configuration SOT996-2

### 6.2 Pin description

Table 3. Pin description

| Symbol | Pin | Description |  |
| :--- | :--- | :--- | :--- |
|  | SOT505-2, SOT765-1, SOT996-2 and <br> SOT833-1 | SOT902-1 |  |
| 1 Y | 1 | 7 | independent input or output |
| $1 Z$ | 2 | 6 | independent input or output |
| 2 E | 3 | 5 | enable input (active HIGH) |
| GND | 4 | 4 | ground (0 V) |
| $2 Y$ | 5 | 3 | independent input or output |
| $2 Z$ | 6 | 2 | independent input or output |
| $1 E$ | 7 | 1 | enable input (active HIGH) |
| $V_{C C}$ | 8 | 8 | supply voltage |

## 7. Functional description

Table 4. Function table [1]

| Input nE | Switch |
| :--- | :--- |
| L | OFF-state |
| H | ON-state |

[1] $\mathrm{H}=$ HIGH voltage level; $\mathrm{L}=$ LOW voltage level.
8. Limiting values

Table 5. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | supply voltage |  | -0.5 | +6.5 | V |
| $V_{1}$ | input voltage |  | [1] -0.5 | +6.5 | V |
| $\mathrm{I}_{\mathrm{IK}}$ | input clamping current | $\mathrm{V}_{1}<-0.5 \mathrm{~V}$ or $\mathrm{V}_{1}>\mathrm{V}_{\mathrm{CC}}+0.5 \mathrm{~V}$ | -50 | - | mA |
| $\mathrm{I}_{\text {SK }}$ | switch clamping current | $V_{1}<-0.5 \mathrm{~V}$ or $\mathrm{V}_{1}>\mathrm{V}_{\mathrm{CC}}+0.5 \mathrm{~V}$ | - | $\pm 50$ | mA |
| $V_{\text {SW }}$ | switch voltage | enable and disable mode | [2] -0.5 | $\mathrm{V}_{\mathrm{CC}}+0.5$ | $\checkmark$ |
| Isw | switch current | $\begin{aligned} & \mathrm{V}_{\mathrm{SW}}>-0.5 \mathrm{~V} \text { or } \\ & \mathrm{V}_{\mathrm{SW}}<\mathrm{V}_{\mathrm{CC}}+0.5 \mathrm{~V} \end{aligned}$ | - | $\pm 50$ | mA |
| $\mathrm{I}_{\mathrm{CC}}$ | supply current |  | - | 100 | mA |
| $\mathrm{I}_{\text {GND }}$ | ground current |  | -100 | - | mA |
| $\mathrm{T}_{\text {stg }}$ | storage temperature |  | -65 | +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{P}_{\text {tot }}$ | total power dissipation | $\mathrm{T}_{\text {amb }}=-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | [3] | 250 | mW |

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.
[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed.
[3] For TSSOP8 package: above $55^{\circ} \mathrm{C}$ the value of $\mathrm{P}_{\text {tot }}$ derates linearly with $2.5 \mathrm{~mW} / \mathrm{K}$. For VSSOP8 package: above $110^{\circ} \mathrm{C}$ the value of $\mathrm{P}_{\text {tot }}$ derates linearly with $8 \mathrm{~mW} / \mathrm{K}$. For XSON8, XSON8U and XQFN8U packages: above $118^{\circ} \mathrm{C}$ the value of $\mathrm{P}_{\text {tot }}$ derates linearly with $7.8 \mathrm{~mW} / \mathrm{K}$.

## 9. Recommended operating conditions

Table 6. Operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
| :--- | :--- | :--- | :--- | :--- | :--- |
| $\mathrm{V}_{\mathrm{CC}}$ | supply voltage |  | 1.65 | 5.5 | V |
| $\mathrm{~V}_{\mathrm{I}}$ | input voltage |  | 0 | 5.5 | V |
| $\mathrm{~V}_{\mathrm{SW}}$ | switch voltage | $\underline{[1][2]}$ | 0 | $\mathrm{~V}_{\mathrm{CC}}$ | V |
| $\mathrm{T}_{\mathrm{amb}}$ | ambient temperature |  | -40 | +125 | ${ }^{\circ} \mathrm{C}$ |
| $\Delta \mathrm{t} / \Delta \mathrm{V}$ | input transition rise and fall rate | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ to 2.7 V | $\underline{[3]}-$ | 20 | $\mathrm{~ns} / \mathrm{V}$ |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ to 5.5 V | $\underline{[3]}-$ | 10 | $\mathrm{~ns} / \mathrm{V}$ |

[1] To avoid sinking GND current from terminal $n Z$ when switch current flows in terminal $n Y$, the voltage drop across the bidirectional switch must not exceed 0.4 V . If the switch current flows into terminal nZ , no GND current will flow from terminal nY . In this case, there is no limit for the voltage drop across the switch.
[2] For overvoltage tolerant switch voltage capability, refer to 74LVCV2G66.
[3] Applies to control signal levels.

## 10. Static characteristics

Table 7. Static characteristics
At recommended operating conditions; voltages are referenced to GND (ground = 0 V ).

| Symbol | Parameter | Conditions |  | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |  |  | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | Typ[1] | Max | Min | Max |  |
| $\mathrm{V}_{\mathrm{IH}}$ | HIGH-level input voltage | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ to 1.95 V |  | $0.65 \times \mathrm{V}_{\mathrm{CC}}$ | - | - | $0.65 \times \mathrm{V}_{\mathrm{CC}}$ | - | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V |  | 1.7 | - | - | 1.7 | - | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ to 3.6 V |  | 2.0 | - | - | 2.0 | - | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V |  | $0.7 \times \mathrm{V}_{\mathrm{CC}}$ | - | - | $0.7 \times \mathrm{V}_{\mathrm{CC}}$ | - | V |
| $\mathrm{V}_{\text {IL }}$ | LOW-level input voltage | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ to 1.95 V |  | - | - | $0.35 \times \mathrm{V}_{\mathrm{CC}}$ | - | $0.35 \times \mathrm{V}_{\mathrm{CC}}$ | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V |  | - | - | 0.7 | - | 0.7 | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ to 3.6 V |  | - | - | 0.8 | - | 0.8 | V |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V |  | - | - | $0.3 \times \mathrm{V}_{\mathrm{CC}}$ | - | $0.3 \times \mathrm{V}_{\mathrm{CC}}$ | V |
| 1 | input leakage current | pin $n E ; V_{l}=5.5 \mathrm{~V}$ or $G N D$; $\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V} \text { to } 5.5 \mathrm{~V}$ | [2] | - | $\pm 0.1$ | $\pm 5$ | - | $\pm 100$ | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {S(OFF) }}$ | OFF-state leakage current | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$; see Figure 8 | [2] | - | $\pm 0.1$ | $\pm 5$ | - | $\pm 200$ | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {(ON }}$ | ON-state leakage current | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$; see $\underline{\text { Figure } 9}$ | [2] | - | $\pm 0.1$ | $\pm 5$ | - | $\pm 200$ | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{CC}}$ | supply current | $\begin{aligned} & \mathrm{V}_{1}=5.5 \mathrm{~V} \text { or } \mathrm{GND} ; \\ & \mathrm{V}_{\mathrm{SW}}=\mathrm{GND} \text { or } \mathrm{V}_{\mathrm{CC}} ; \\ & \mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{aligned}$ | [2] | - | 0.1 | 10 | - | 200 | $\mu \mathrm{A}$ |
| $\Delta l_{\text {CC }}$ | additional supply current | $\begin{aligned} & \operatorname{pin} n E ; V_{I}=V_{C C}-0.6 \mathrm{~V} ; \\ & V_{S W}=G N D \text { or } V_{C C} ; \\ & V_{C C}=5.5 \mathrm{~V} \end{aligned}$ | [2] | - | 5 | 500 | - | 5000 | $\mu \mathrm{A}$ |

Table 7. Static characteristics ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V ).

| Symbol | Parameter | Conditions | $-40^{\circ} \mathrm{C}$ to $+85{ }^{\circ} \mathrm{C}$ |  |  | $-40{ }^{\circ} \mathrm{C}$ to $+125{ }^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Typ[1] | Max | Min | Max |  |
| $\mathrm{Cl}_{1}$ | input capacitance |  | - | 2.0 | - | - | - | pF |
| $\mathrm{C}_{\text {S(OFF) }}$ | OFF-state capacitance |  | - | 5.0 | - | - | - | pF |
| $\mathrm{C}_{\mathrm{S}(\mathrm{ON})}$ | ON-state capacitance |  | - | 9.5 | - | - | - | pF |

[1] All typical values are measured at $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$.
[2] These typical values are measured at $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}$.

### 10.1 Test circuits



### 10.2 ON resistance

Table 8. ON resistance At recommended operating conditions; voltages are referenced to GND (ground 0 V ); for graphs see Figure 11 to Figure 16.

| Symbol | Parameter | Conditions | $-40{ }^{\circ} \mathrm{C}$ to $+85{ }^{\circ} \mathrm{C}$ |  |  | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Typ[1] | Max | Min | Max |  |
| $\mathrm{R}_{\text {ON(peak })}$ | ON resistance (peak) | $\mathrm{V}_{\mathrm{I}}=\mathrm{GND}$ to $\mathrm{V}_{\mathrm{Cc}}$; see Figure 10 |  |  |  |  |  |  |
|  |  | $\begin{aligned} & \mathrm{I}_{\mathrm{SW}}=4 \mathrm{~mA} ; \\ & \mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V} \text { to } 1.95 \mathrm{~V} \end{aligned}$ | - | 34.0 | 130 | - | 195 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=8 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | - | 12.0 | 30 | - | 45 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=12 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | - | 10.4 | 25 | - | 38 | $\Omega$ |
|  |  | $\mathrm{I}_{\text {SW }}=24 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ to 3.6 V | - | 7.8 | 20 | - | 30 | $\Omega$ |
|  |  | $\mathrm{I}_{\text {SW }}=32 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | - | 6.2 | 15 | - | 23 | $\Omega$ |
| $\mathrm{R}_{\mathrm{ON}(\text { rail }}$ | ON resistance (rail) | $V_{1}=$ GND; see Figure 10 |  |  |  |  |  |  |
|  |  | $\begin{aligned} & \mathrm{I}_{\mathrm{SW}}=4 \mathrm{~mA} ; \\ & \mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V} \text { to } 1.95 \mathrm{~V} \end{aligned}$ | - | 8.2 | 18 | - | 27 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=8 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | - | 7.1 | 16 | - | 24 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{sw}}=12 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | - | 6.9 | 14 | - | 21 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=24 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ to 3.6 V | - | 6.5 | 12 | - | 18 | $\Omega$ |
|  |  | $\mathrm{I}_{\text {SW }}=32 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | - | 5.8 | 10 | - | 15 | $\Omega$ |
|  |  | $V_{I}=V_{C C} \text {; see Figure } 10$ |  |  |  |  |  |  |
|  |  | $\begin{aligned} & \mathrm{I}_{\mathrm{SW}}=4 \mathrm{~mA} ; \\ & \mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V} \text { to } 1.95 \mathrm{~V} \end{aligned}$ | - | 10.4 | 30 | - | 45 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=8 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | - | 7.6 | 20 | - | 30 | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{Sw}}=12 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | - | 7.0 | 18 | - | 27 | $\Omega$ |
|  |  | $\mathrm{I}_{\text {SW }}=24 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ to 3.6 V | - | 6.1 | 15 | - | 23 | $\Omega$ |
|  |  | $\mathrm{I}_{\text {SW }}=32 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | - | 4.9 | 10 | - | 15 | $\Omega$ |
| $\mathrm{R}_{\mathrm{ON} \text { (flat) }}$ | ON resistance (flatness) | $\mathrm{V}_{\mathrm{I}}=\mathrm{GND}$ to $\mathrm{V}_{\mathrm{CC}}$ |  |  |  |  |  |  |
|  |  | $\begin{aligned} & \mathrm{I}_{\mathrm{SW}}=4 \mathrm{~mA} ; \\ & \mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V} \text { to } 1.95 \mathrm{~V} \end{aligned}$ | - | 26.0 | - | - | - | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=8 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ to 2.7 V | - | 5.0 | - | - | - | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{sw}}=12 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$ | - | 3.5 | - | - | - | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=24 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ to 3.6 V | - | 2.0 | - | - | - | $\Omega$ |
|  |  | $\mathrm{I}_{\mathrm{SW}}=32 \mathrm{~mA} ; \mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to 5.5 V | - | 1.5 | - | - | - | $\Omega$ |

[1] Typical values are measured at $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ and nominal $\mathrm{V}_{\mathrm{CC}}$.
[2] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical $\mathrm{V}_{\mathrm{CC}}$ and temperature.

### 10.3 ON resistance test circuit and graphs


$\mathrm{R}_{\mathrm{ON}}=\mathrm{V}_{\mathrm{SW}} / \mathrm{I}_{\mathrm{SW}}$.

Fig 10. Test circuit for measuring ON resistance

(1) $\mathrm{T}_{\text {amb }}=125^{\circ} \mathrm{C}$.
(2) $\mathrm{T}_{\text {amb }}=85^{\circ} \mathrm{C}$.
(3) $\mathrm{T}_{\text {amb }}=25^{\circ} \mathrm{C}$.
(4) $\mathrm{T}_{\text {amb }}=-40^{\circ} \mathrm{C}$.

Fig 12. ON resistance as a function of input voltage; $\mathrm{V}_{\mathrm{cc}}=1.8 \mathrm{~V}$

(1) $\mathrm{V}_{\mathrm{CC}}=1.8 \mathrm{~V}$.
(2) $\mathrm{V}_{\mathrm{Cc}}=2.5 \mathrm{~V}$.
(3) $\mathrm{V}_{\mathrm{CC}}=2.7 \mathrm{~V}$.
(4) $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}$.
(5) $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$.

Fig 11. Typical ON resistance as a function of input voltage; $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$

(1) $\mathrm{T}_{\text {amb }}=125^{\circ} \mathrm{C}$.
(2) $\mathrm{T}_{\text {amb }}=85^{\circ} \mathrm{C}$.
(3) $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$.
(4) $\mathrm{T}_{\mathrm{amb}}=-40^{\circ} \mathrm{C}$.

Fig 13. ON resistance as a function of input voltage; $\mathrm{V}_{\mathrm{Cc}}=2.5 \mathrm{~V}$

(1) $\mathrm{T}_{\mathrm{amb}}=125^{\circ} \mathrm{C}$.
(2) $\mathrm{T}_{\text {amb }}=85^{\circ} \mathrm{C}$.
(3) $\mathrm{T}_{\text {amb }}=25^{\circ} \mathrm{C}$.
(4) $\mathrm{T}_{\text {amb }}=-40^{\circ} \mathrm{C}$.

Fig 14. ON resistance as a function of input voltage; $\mathrm{V}_{\mathrm{cc}}=2.7 \mathrm{~V}$

(1) $\mathrm{T}_{\mathrm{amb}}=125^{\circ} \mathrm{C}$.
(2) $\mathrm{T}_{\text {amb }}=85^{\circ} \mathrm{C}$.
(3) $\mathrm{T}_{\text {amb }}=25^{\circ} \mathrm{C}$.
(4) $\mathrm{T}_{\text {amb }}=-40^{\circ} \mathrm{C}$.

Fig 15. ON resistance as a function of input voltage; $\mathrm{V}_{\mathrm{cc}}=3.3 \mathrm{~V}$

(1) $\mathrm{T}_{\mathrm{amb}}=125^{\circ} \mathrm{C}$.
(2) $\mathrm{T}_{\mathrm{amb}}=85^{\circ} \mathrm{C}$.
(3) $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$.
(4) $\mathrm{T}_{\mathrm{amb}}=-40^{\circ} \mathrm{C}$.

Fig 16. ON resistance as a function of input voltage; $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$

## 11. Dynamic characteristics

Table 9. Dynamic characteristics
At recommended operating conditions; voltages are referenced to GND (ground $=0 \mathrm{~V}$ ); for test circuit see Figure 19.

[1] Typical values are measured at $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ and nominal $\mathrm{V}_{\mathrm{cc}}$.
[2] $t_{p d}$ is the same as $t_{\text {pLH }}$ and $t_{\text {PHL }}$.
[3] Propagation delay is the calculated RC time constant of the typical ON resistance of the switch and the specified capacitance when driven by an ideal voltage source (zero output impedance).
[4] $t_{e n}$ is the same as $t_{p z h}$ and $t_{\text {PzL }}$.
[5] $t_{\text {dis }}$ is the same as $t_{\text {PLZ }}$ and $t_{\text {PHZ }}$.
[6] $C_{P D}$ is used to determine the dynamic power dissipation ( $P_{D}$ in $\mu \mathrm{W}$ ).
$P_{D}=C_{P D} \times V_{C C}{ }^{2} \times f_{i} \times N+\Sigma\left\{\left(C_{L}+C_{S(O N)}\right) \times V_{C C}{ }^{2} \times f_{o}\right\}$ where:
$\mathrm{f}_{\mathrm{i}}=$ input frequency in MHz ;
$\mathrm{f}_{\mathrm{o}}=$ output frequency in MHz ;
$\mathrm{C}_{\mathrm{L}}=$ output load capacitance in pF ;
$\mathrm{C}_{\mathrm{S}(\mathrm{ON})}=$ maximum ON -state switch capacitance in pF ;
$\mathrm{V}_{\mathrm{CC}}=$ supply voltage in V ;
$\mathrm{N}=$ number of inputs switching;
$\Sigma\left\{\left(\mathrm{C}_{\mathrm{L}}+\mathrm{C}_{\mathrm{S}(\mathrm{ON})}\right) \times \mathrm{V}_{\mathrm{CC}}{ }^{2} \times \mathrm{f}_{\mathrm{o}}\right\}=$ sum of the outputs.

### 11.1 Waveforms and test circuit



Measurement points are given in Table 10.
Logic levels: $\mathrm{V}_{\mathrm{OL}}$ and $\mathrm{V}_{\mathrm{OH}}$ are typical output voltage levels that occur with the output load.
Fig 17. Input ( $\mathrm{n} Y$ or nZ ) to output ( nZ or nY ) propagation delays


Measurement points are given in Table 10.
Logic levels: $\mathrm{V}_{\mathrm{OL}}$ and $\mathrm{V}_{\mathrm{OH}}$ are typical output voltage levels that occur with the output load.
Fig 18. Enable and disable times

Table 10. Measurement points

| Supply voltage | Input | Output |  |  |
| :--- | :--- | :--- | :--- | :--- |
| $\mathbf{V}_{\mathrm{CC}}$ | $\mathbf{V}_{\mathrm{M}}$ | $\mathbf{V}_{\mathrm{M}}$ | $\mathbf{V}_{\mathbf{X}}$ | $\mathbf{V}_{\mathbf{Y}}$ |
| 1.65 V to 1.95 V | $0.5 \times \mathrm{V}_{\mathrm{CC}}$ | $0.5 \times \mathrm{V}_{\mathrm{CC}}$ | $\mathrm{V}_{\mathrm{OL}}+0.15 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{OH}}-0.15 \mathrm{~V}$ |
| 2.3 V to 2.7 V | $0.5 \times \mathrm{V}_{\mathrm{CC}}$ | $0.5 \times \mathrm{V}_{\mathrm{CC}}$ | $\mathrm{V}_{\mathrm{OL}}+0.15 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{OH}}-0.15 \mathrm{~V}$ |
| 2.7 V | 1.5 V | 1.5 V | $\mathrm{~V}_{\mathrm{OL}}+0.3 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{OH}}-0.3 \mathrm{~V}$ |
| 3.0 V to 3.6 V | 1.5 V | 1.5 V | $\mathrm{~V}_{\mathrm{OL}}+0.3 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{OH}}-0.3 \mathrm{~V}$ |
| 4.5 V to 5.5 V | $0.5 \times \mathrm{V}_{\mathrm{CC}}$ | $0.5 \times \mathrm{V}_{\mathrm{CC}}$ | $\mathrm{V}_{\mathrm{OL}}+0.3 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{OH}}-0.3 \mathrm{~V}$ |



Test data is given in Table 11.
Definitions for test circuit:
$R_{L}=$ Load resistor.
$C_{L}=$ Load capacitance including jig and probe capacitance.
$R_{T}=$ Termination resistance should be equal to output impedance $Z_{o}$ of the pulse generator.
$\mathrm{V}_{\mathrm{EXT}}=$ Test voltage for switching times.
Fig 19. Test circuit for measuring switching times

Table 11. Test data

| Supply voltage | Input |  | Load |  | $\mathrm{V}_{\text {EXT }}$ |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{cc}}$ | $\mathrm{V}_{\mathbf{I}}$ | $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}$ | $\mathrm{C}_{\mathrm{L}}$ | $\mathbf{R}_{\mathrm{L}}$ | $\mathrm{t}_{\text {PLH, }} \mathrm{t}_{\text {PHL }}$ | $\mathbf{t}_{\text {PZH, }} \mathbf{t}_{\text {PHZ }}$ | $\mathbf{t}_{\text {PZL, }}, \mathrm{t}_{\text {PLZ }}$ |
| 1.65 V to 1.95 V | $\mathrm{V}_{\mathrm{Cc}}$ | $\leq 2.0 \mathrm{~ns}$ | 30 pF | $1 \mathrm{k} \Omega$ | open | GND | $2 \times \mathrm{V}_{\mathrm{Cc}}$ |
| 2.3 V to 2.7 V | $\mathrm{V}_{\text {cc }}$ | $\leq 2.0 \mathrm{~ns}$ | 30 pF | $500 \Omega$ | open | GND | $2 \times \mathrm{V}_{\mathrm{CC}}$ |
| 2.7 V | 2.7 V | $\leq 2.5$ ns | 50 pF | $500 \Omega$ | open | GND | 6 V |
| 3.0 V to 3.6 V | 2.7 V | $\leq 2.5 \mathrm{~ns}$ | 50 pF | $500 \Omega$ | open | GND | 6 V |
| 4.5 V to 5.5 V | $\mathrm{V}_{\mathrm{CC}}$ | $\leq 2.5 \mathrm{~ns}$ | 50 pF | $500 \Omega$ | open | GND | $2 \times \mathrm{V}_{\mathrm{CC}}$ |

### 11.2 Additional dynamic characteristics

Table 12. Additional dynamic characteristics
At recommended operating conditions; voltages are referenced to GND (ground $=0 \mathrm{~V}$ ); $T_{a m b}=25{ }^{\circ} \mathrm{C}$.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| THD | total harmonic distortion | $\mathrm{R}_{\mathrm{L}}=10 \mathrm{k}$; $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} ; \mathrm{f}_{\mathrm{i}}=1 \mathrm{kHz}$; see $\underline{\text { Figure } 20}$ |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ | - | 0.032 | - | \% |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ | - | 0.008 | - | \% |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ | - | 0.006 | - | \% |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | - | 0.005 | - | \% |
|  |  | $\mathrm{R}_{\mathrm{L}}=10 \mathrm{k} \Omega ; \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} ; \mathrm{f}_{\mathrm{i}}=10 \mathrm{kHz}$; see Figure 20 |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ | - | 0.068 | - | \% |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ | - | 0.009 | - | \% |
|  |  | $\mathrm{V}_{\mathrm{Cc}}=3.0 \mathrm{~V}$ | - | 0.008 | - | \% |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | - | 0.006 | - | \% |
| $\mathrm{f}_{(-3 \mathrm{~dB})}$ | -3 dB frequency response | $\mathrm{R}_{\mathrm{L}}=600 \Omega ; \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$; see Figure 21 |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ | - | 135 | - | MHz |
|  |  | $\mathrm{V}_{\mathrm{Cc}}=2.3 \mathrm{~V}$ | - | 145 | - | MHz |
|  |  | $\mathrm{V}_{\mathrm{Cc}}=3.0 \mathrm{~V}$ | - | 150 | - | MHz |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | - | 155 | - | MHz |
|  |  | $\mathrm{R}_{\mathrm{L}}=50 \Omega ; \mathrm{C}_{\mathrm{L}}=10 \mathrm{pF}$; see Figure 21 |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ | - | 200 | - | MHz |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ | - | 350 | - | MHz |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ | - | 410 | - | MHz |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | - | 440 | - | MHz |
|  |  | $\mathrm{R}_{\mathrm{L}}=50 \Omega ; \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}$; see Figure 21 |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ | - | $>500$ | - | MHz |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ | - | $>500$ | - | MHz |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ | - | $>500$ | - | MHz |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | - | > 500 | - | MHz |
| $\alpha_{\text {iso }}$ | isolation (OFF-state) | $\mathrm{R}_{\mathrm{L}}=600 \Omega ; \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} ; \mathrm{f}_{\mathrm{i}}=1 \mathrm{MHz}$; see $\underline{\text { Figure } 22}$ |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ | - | -46 | - | dB |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ | - | -46 | - | dB |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ | - | -46 | - | dB |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | - | -46 | - | dB |
|  |  | $\mathrm{R}_{\mathrm{L}}=50 \Omega ; \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF} ; \mathrm{f}_{\mathrm{i}}=1 \mathrm{MHz}$; see Figure 22 |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ | - | -37 | - | dB |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ | - | -37 | - | dB |
|  |  | $\mathrm{V}_{\mathrm{Cc}}=3.0 \mathrm{~V}$ | - | -37 | - | dB |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | - | -37 | - | dB |

Table 12. Additional dynamic characteristics ...continued
At recommended operating conditions; voltages are referenced to GND (ground $=0 \mathrm{~V}$ ); $T_{a m b}=25{ }^{\circ} \mathrm{C}$.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {ct }}$ | crosstalk voltage | between digital inputs and switch; $\mathrm{R}_{\mathrm{L}}=600 \Omega$; $C_{L}=50 \mathrm{pF} ; \mathrm{f}_{\mathrm{i}}=1 \mathrm{MHz} ; \mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=2 \mathrm{~ns}$; see Figure 23 |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ | - | - | - | mV |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ | - | 91 | - | mV |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ | - | 119 | - | mV |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | - | 205 | - | mV |
| Xtalk | crosstalk | between switches; $\mathrm{R}_{\mathrm{L}}=600 \Omega ; \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$; $f_{i}=1 \mathrm{MHz}$; see Figure 24 |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ | - | - | - | dB |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ | - | -56 | - | dB |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ | - | -56 | - | dB |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | - | -56 | - | dB |
|  |  | between switches; $\mathrm{R}_{\mathrm{L}}=50 \Omega ; \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}$; $f_{i}=1 \mathrm{MHz}$; see Figure 24 |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ | - | - | - | dB |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}$ | - | -29 | - | dB |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}$ | - | -28 | - | dB |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | - | -28 | - | dB |
| Qinj | charge injection | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=0.1 \mathrm{nF} ; \mathrm{V}_{\text {gen }}=0 \mathrm{~V} ; \mathrm{R}_{\text {gen }}=0 \Omega ; \mathrm{f}_{\mathrm{i}}=1 \mathrm{MHz} ; \\ & \mathrm{R}_{\mathrm{L}}=1 \mathrm{M} \Omega ; \text { see Figure } 25 \end{aligned}$ |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=1.8 \mathrm{~V}$ | - | 3.3 | - | pC |
|  |  | $\mathrm{V}_{\mathrm{CC}}=2.5 \mathrm{~V}$ | - | 4.1 | - | pC |
|  |  | $\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V}$ | - | 5.0 | - | pC |
|  |  | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | - | 6.4 | - | pC |
|  |  | $\mathrm{V}_{\mathrm{CC}}=5.5 \mathrm{~V}$ | - | 7.5 | - | pC |

### 11.3 Test circuits



Test conditions:
$\mathrm{V}_{\mathrm{CC}}=1.65 \mathrm{~V}$ : $\mathrm{V}_{\mathrm{i}}=1.4 \mathrm{~V}(\mathrm{p}-\mathrm{p})$.
$\mathrm{V}_{\mathrm{CC}}=2.3 \mathrm{~V}: \mathrm{V}_{\mathrm{i}}=2 \mathrm{~V}(\mathrm{p}-\mathrm{p})$.
$\mathrm{V}_{\mathrm{CC}}=3 \mathrm{~V}: \mathrm{V}_{\mathrm{i}}=2.5 \mathrm{~V}(\mathrm{p}-\mathrm{p})$.
$\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}: \mathrm{V}_{\mathrm{i}}=4 \mathrm{~V}(\mathrm{p}-\mathrm{p})$.
Fig 20. Test circuit for measuring total harmonic distortion


Adjust $f_{i}$ voltage to obtain 0 dBm level at output. Increase $\mathrm{f}_{\mathrm{i}}$ frequency until dB meter reads -3 dB .
Fig 21. Test circuit for measuring the frequency response when switch is in ON-state


Adjust $\mathrm{f}_{\mathrm{i}}$ voltage to obtain 0 dBm level at input.
Fig 22. Test circuit for measuring isolation (OFF-state)


Fig 23. Test circuit for measuring crosstalk voltage (between digital inputs and switch)

$20 \log _{10}\left(V_{\mathrm{O} 2} / \mathrm{V}_{\mathrm{O} 1}\right)$ or $20 \log _{10}\left(\mathrm{~V}_{\mathrm{O} 1} / \mathrm{V}_{\mathrm{O} 2}\right)$.
Fig 24. Test circuit for measuring crosstalk between switches

a. Test circuit

$v_{0}$

b. Input and output pulse definitions
$\mathrm{Q}_{\mathrm{inj}}=\Delta \mathrm{V}_{\mathrm{O}} \times \mathrm{C}_{\mathrm{L}}$.
$\Delta \mathrm{V}_{\mathrm{O}}=$ output voltage variation.
$\mathrm{R}_{\text {gen }}=$ generator resistance.
$\mathrm{V}_{\text {gen }}=$ generator voltage.
Fig 25. Test circuit for measuring charge injection

## 12. Package outline



DIMENSIONS (mm are the original dimensions)

| UNIT | $\begin{gathered} \mathrm{A} \\ \max . \end{gathered}$ | $\mathrm{A}_{1}$ | $\mathrm{A}_{2}$ | $\mathrm{A}_{3}$ | $\mathrm{b}_{\mathrm{p}}$ | c | $D^{(1)}$ | $E^{(1)}$ | e | $\mathrm{H}_{\mathrm{E}}$ | L | $L_{p}$ | v | w | y | $Z^{(1)}$ | $\theta$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| mm | 1.1 | $\begin{aligned} & 0.15 \\ & 0.00 \end{aligned}$ | $\begin{aligned} & 0.95 \\ & 0.75 \end{aligned}$ | 0.25 | $\begin{aligned} & 0.38 \\ & 0.22 \end{aligned}$ | $\begin{aligned} & 0.18 \\ & 0.08 \end{aligned}$ | $\begin{aligned} & 3.1 \\ & 2.9 \end{aligned}$ | $\begin{aligned} & 3.1 \\ & 2.9 \end{aligned}$ | 0.65 | $\begin{aligned} & 4.1 \\ & 3.9 \end{aligned}$ | 0.5 | $\begin{aligned} & 0.47 \\ & 0.33 \end{aligned}$ | 0.2 | 0.13 | 0.1 | $\begin{aligned} & 0.70 \\ & 0.35 \end{aligned}$ | $8^{\circ}{ }^{\circ}$ |

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

| OUTLINE <br> VERSION | REFERENCES |  |  |  | EUROPEAN <br> PROJECTION | ISSUE DATE |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
|  | IEC | JEDEC | JEITA |  |  |  |
| SOT505-2 |  | $\ldots$ |  |  | $02-01-16$ |  |

Fig 26. Package outline SOT505-2 (TSSOP8)


DIMENSIONS (mm are the original dimensions)

| UNIT | $\mathbf{A}$ <br> max. | $\mathbf{A}_{\mathbf{1}}$ | $\mathbf{A}_{\mathbf{2}}$ | $\mathbf{A}_{\mathbf{3}}$ | $\mathbf{b}_{\mathbf{p}}$ | $\mathbf{c}$ | $\mathbf{D}^{(\mathbf{1})}$ | $\mathbf{E}^{(\mathbf{2})}$ | $\mathbf{e}$ | $\mathbf{H}_{\mathbf{E}}$ | $\mathbf{L}$ | $\mathbf{L}_{\mathbf{p}}$ | $\mathbf{Q}$ | $\mathbf{v}$ | $\mathbf{w}$ | $\mathbf{y}$ | $\mathbf{Z}^{(1)}$ | $\boldsymbol{\theta}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| mm | 1 | 0.15 | 0.85 | 0.12 | 0.27 | 0.23 | 2.1 | 2.4 | 0.5 | 3.2 | 0.4 | 0.40 | 0.21 | 0.2 | 0.13 | 0.1 | 0.4 | $8^{\circ}$ |
|  | 0.00 | 0.60 | 0.17 | 0.08 | 1.9 | 2.2 | 0.5 | 3.0 | 0.4 | 0.15 | 0.19 | 0.1 | $0^{\circ}$ |  |  |  |  |  |

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

| OUTLINE <br> VERSION | REFERENCES |  |  |  | EUROPEAN | ISSUE DATE |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
|  | IEC | JEDEC | JEITA |  |  |  |

Fig 27. Package outline SOT765-1 (VSSOP8)


DIMENSIONS (mm are the original dimensions)

| UNIT | $\mathbf{A}^{(1)}$ <br> $\max$ | $\mathbf{A}_{\mathbf{1}}$ <br> $\boldsymbol{m a x}$ | $\mathbf{b}$ | $\mathbf{D}$ | $\mathbf{E}$ | $\mathbf{e}$ | $\mathbf{e}_{\mathbf{1}}$ | $\mathbf{L}$ | $\mathbf{L}_{\mathbf{1}}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| mm | 0.5 | 0.04 | 0.25 <br> 0.17 | 2.0 <br> 1.9 | 1.05 <br> 0.95 | 0.6 | 0.5 | 0.35 | 0.40 |
| 0.27 | 0.32 |  |  |  |  |  |  |  |  |

Notes

1. Including plating thickness.
2. Can be visible in some manufacturing processes.

| OUTLINE VERSION | REFERENCES |  |  | EUROPEAN PROJECTION | ISSUE DATE |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | IEC | JEDEC | JEITA |  |  |
| SOT833-1 | - | MO-252 | --- | $\square$ (¢) | $\begin{aligned} & 07-11-14 \\ & 07-12-07 \end{aligned}$ |

Fig 28. Package outline SOT833-1 (XSON8)


| OUTLINE <br> VERSION | REFERENCES |  |  |  | EUROPEAN <br> PROJECTION | ISSUE DATE |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | IEC | JEDEC | JEITA |  |  |  |
| SOT996-2 | -- |  | - |  | $07-12-18$ |  |

Fig 29. Package outline SOT996-2 (XSON8U)



## DIMENSIONS (mm are the original dimensions)

| UNIT | $\mathbf{A}$ <br> $\boldsymbol{m a x}$ | $\mathbf{A}_{\mathbf{1}}$ | $\mathbf{b}$ | $\mathbf{D}$ | $\mathbf{E}$ | $\mathbf{e}$ | $\mathbf{e}_{\mathbf{1}}$ | $\mathbf{L}$ | $\mathbf{L}_{\mathbf{1}}$ | $\mathbf{v}$ | $\mathbf{w}$ | $\mathbf{y}$ | $\mathbf{y}_{\mathbf{1}}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| mm | 0.5 | 0.05 | 0.25 | 1.65 | 1.65 | 0.55 | 0.5 | 0.35 <br> 0.25 | 0.15 <br> 0.05 | 0.1 | 0.05 | 0.05 | 0.05 |


| OUTLINE VERSION | REFERENCES |  |  | EUROPEAN PROJECTION | ISSUE DATE |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | IEC | JEDEC | JEITA |  |  |
| SOT902-1 | --- | MO-255 | --- | $\bigcirc$ | $\begin{aligned} & 05-11-25 \\ & 07-11-14 \end{aligned}$ |

Fig 30. Package outline SOT902-1 (XQFN8U)

## 13. Abbreviations

Table 13. Abbreviations

| Acronym | Description |
| :--- | :--- |
| CMOS | Complementary Metal-Oxide Semiconductor |
| TTL | Transistor-Transistor Logic |
| HBM | Human Body Model |
| ESD | ElectroStatic Discharge |
| MM | Machine Model |
| DUT | Device Under Test |

## 14. Revision history

Table 14. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| :---: | :---: | :---: | :---: | :---: |
| 74LVC2G66 v. 5 | 20100616 | Product data sheet | - | 74LVC2G66 v. 4 |
| Modifications: | - Conditions for $\mathrm{I}_{\mathrm{CC}}$ and $\Delta \mathrm{I}_{\mathrm{CC}}$ corrected. |  |  |  |
| 74LVC2G66 v. 4 | 20080701 | Product data sheet | - | 74LVC2G66 v. 3 |
| 74LVC2G66 v. 3 | 20080310 | Product data sheet | - | 74LVC2G66 v. 2 |
| 74LVC2G66 v. 2 | 20070828 | Product data sheet | - | 74LVC2G66 v. 1 |
| 74LVC2G66 v. 1 | 20040629 | Product data sheet | - | - |

## 15. Legal information

### 15.1 Data sheet status

| Document $\operatorname{status} \underline{[1][2]}$ | Product status $\underline{[3]}$ | Definition |
| :--- | :--- | :--- |
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.
[2] The term 'short data sheet' is explained in section "Definitions".
[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

### 15.2 Definitions

Draft - The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet - A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification - The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

### 15.3 Disclaimers

Limited warranty and liability - Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.
Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of NXP Semiconductors.
Right to make changes - NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.
Suitability for use in automotive applications - This NXP
Semiconductors product has been qualified for use in automotive applications. The product is not designed, authorized or warranted to be
suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications - Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.
Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.
NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values - Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.
Terms and conditions of commercial sale - NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.
No offer to sell or license - Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control - This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

### 15.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

## 16. Contact information

For more information, please visit: http://www.nxp.com
For sales office addresses, please send an email to: salesaddresses@nxp.com

## 17. Contents

1 General description. . . . . . . . . . . . . . . . . . . . . 1
2 Features and benefits . . . . . . . . . . . . . . . . . . . . 1
3 Ordering information. . . . . . . . . . . . . . . . . . . . . 2
4 Marking. . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 2
5 Functional diagram . . . . . . . . . . . . . . . . . . . . . . 2
6 Pinning information. . . . . . . . . . . . . . . . . . . . . 3
6.1 Pinning . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 3
6.2 Pin description . . . . . . . . . . . . . . . . . . . . . . . . . . 4

7 Functional description ...................... . . . 4
8 Limiting values. . . . . . . . . . . . . . . . . . . . . . . . . . . 4
9 Recommended operating conditions. . . . . . . . 5
10 Static characteristics. . . . . . . . . . . . . . . . . . . . . . 5
10.1 Test circuits. . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 6
10.2 ON resistance . . . . . . . . . . . . . . . . . . . . . . . . . . . 7
10.3 ON resistance test circuit and graphs. . . . . . . . 8

11 Dynamic characteristics . . . . . . . . . . . . . . . . . 10
11.1 Waveforms and test circuit . . . . . . . . . . . . . . . . 11
11.2 Additional dynamic characteristics . . . . . . . . . . 13
11.3 Test circuits . . . . . . . . . . . . . . . . . . . . . . . . . . . . 15

12 Package outline . . . . . . . . . . . . . . . . . . . . . . . . . 18
13 Abbreviations................................. . . 23
14 Revision history. . . . . . . . . . . . . . . . . . . . . . . . 23
15 Legal information. . . . . . . . . . . . . . . . . . . . . . . . 24
15.1 Data sheet status . . . . . . . . . . . . . . . . . . . . . . . . 24
15.2 Definitions. . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 24
15.3 Disclaimers . . . . . . . . . . . . . . . . . . . . . . . . . . . . 24
15.4 Trademarks. . . . . . . . . . . . . . . . . . . . . . . . . . . . 25

16 Contact information. . . . . . . . . . . . . . . . . . . . . . . 25
17 Contents . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 26

